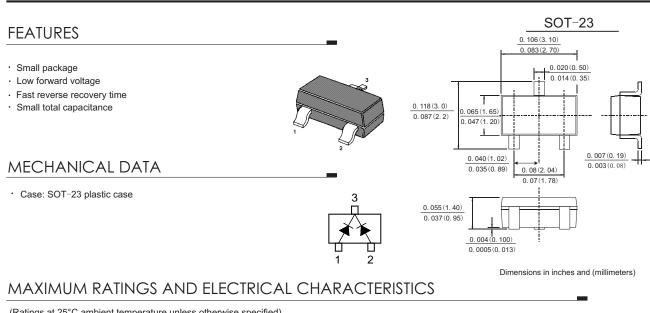


1SS184 SMALL SIGNAL SWITCHING DIODE



(Ratings at 25°C ambient temperature unless otherwise specified)

	Symbols	Value	Units
Maximum Peak Reverse Voltage	Vrm	85	V
Reverse Voltage	VR	80	V
Average Forward Current	lo	100	mA
Maximum Peak Forward Current	Іғм	300	mA
Peak Forward Surge Current(10ms)	IFSM	2	A
Power dissipation	Ptot	150	mW
Junction temperature	TJ	150	°C
Storage temperature range	Тята	-55 to +150	°C

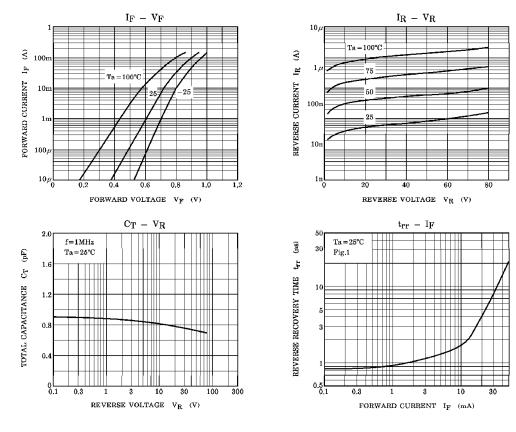
ELECTRICAL CHARACTERISTICS

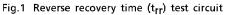
(Ratings at 25°C ambient temperature unless otherwise specified)

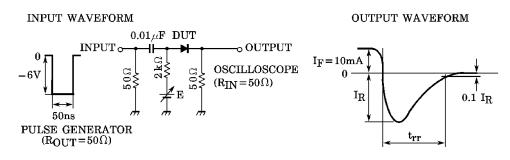
	Symbol	Min.	Тур.	Max.	Units
Forward voltage at IF=100mA	VF			1.2	V
Leakage current at VR=30V	lr			0. 1	μA
Leakage current at VR=80V	IR			0.5	μA
Junction capacitance at VR=0V f=1MHz	CJ			3	pF
Reverse recovery time IF=10mA	trr			4	ns

2-1

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